TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOS IV)

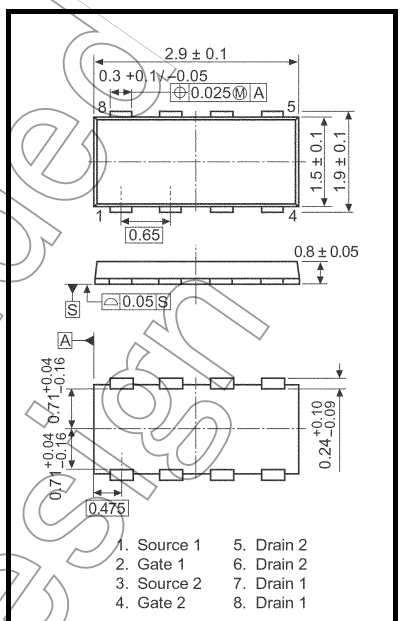
TPCF8302

Notebook PC Applications

Portable Equipment Applications

- Low drain-source ON resistance: $R_{DS\ (ON)}$ = 44 mΩ (typ.)
- High forward transfer admittance: $|Y_{fs}|$ = 6.2 S (typ.)
- Low leakage current: I_{DSS} = −10 μA (max) (V_{DS} = −20 V)
- Enhancement mode: V_{th} = −0.5 to −1.2 V (V_{DS} = −10 V, I_D = −200 μA)

Unit: mm



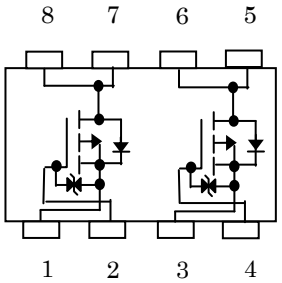
JEDEC	—
JEITA	—
TOSHIBA	2-3U1B

Weight: 0.011 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	−20	V
Drain-gate voltage (R_{GS} = 20 kΩ)		V_{DGR}	−20	V
Gate-source voltage		V_{GSS}	±10	V
Drain current	DC (Note 1)	I_D	−3.0	A
	Pulse (Note 1)	I_{DP}	−12	
Drain power dissipation (t = 5 s) (Note 2a)	Single-device operation (Note 3a)	$P_{D\ (1)}$	1.35	W
	Single-device value at dual operation (Note 3b)	$P_{D\ (2)}$	1.12	
Drain power dissipation (t = 5 s) (Note 2b)	Single-device operation (Note 3a)	$P_{D\ (1)}$	0.53	
	Single-device value at dual operation (Note 3b)	$P_{D\ (2)}$	0.33	
Single pulse avalanche energy (Note 4)		E_{AS}	0.58	mJ
Avalanche current		I_{AR}	−1.5	A
Repetitive avalanche energy Single-device value at dual operation (Note 2a, 3b, 5)		E_{AR}	0.11	mJ
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	−55 to 150	°C

Circuit Configuration



Note: (Note 1), (Note 2), (Note 3), (Note 4) and (Note 5): See the next page.

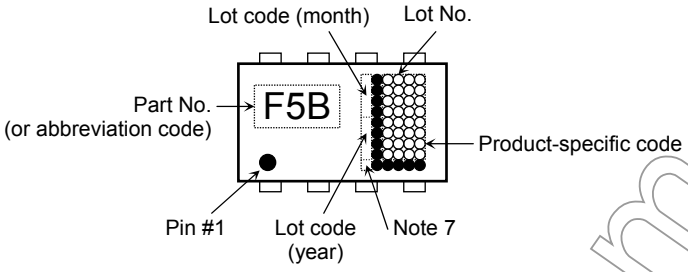
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Please handle with caution.

Thermal Characteristics

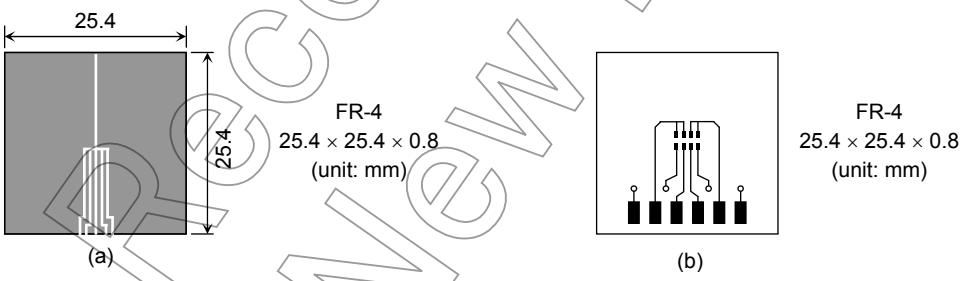
Characteristics		Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 5 s) (Note 2a)	Single-device operation (Note 3a)	$R_{th\ (ch\text{-}a)\ (1)}$	92.6	°C/W
	Single-device value at dual operation (Note 3b)	$R_{th\ (ch\text{-}a)\ (2)}$	111.6	
Thermal resistance, channel to ambient (t = 5 s) (Note 2b)	Single-device operation (Note 3a)	$R_{th\ (ch\text{-}a)\ (1)}$	235.8	°C/W
	Single-device value at dual operation (Note 3b)	$R_{th\ (ch\text{-}a)\ (2)}$	378.8	

Marking (Note 6)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



Note 3: a) The power dissipation and thermal resistance values are shown for a single device (During single-device operation, power is only applied to one device.).
b) The power dissipation and thermal resistance values are shown for a single device (During dual operation, power is evenly applied to both devices.).

Note 4: V_{DD} = −16 V, T_{ch} = 25°C (initial), L = 0.5 mH, R_G = 25 Ω, I_{AR} = −1.5 A

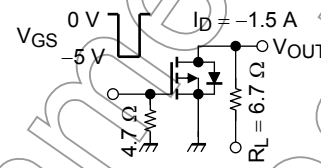
Note 5: Repetitive rating: pulse width limited by maximum channel temperature

Note 6: ● on the lower left of the marking indicates Pin 1.

Note 7: A dot marking identifies the indication of product Labels.
Without a dot: [[Pb]]/INCLUDES > MCV
With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

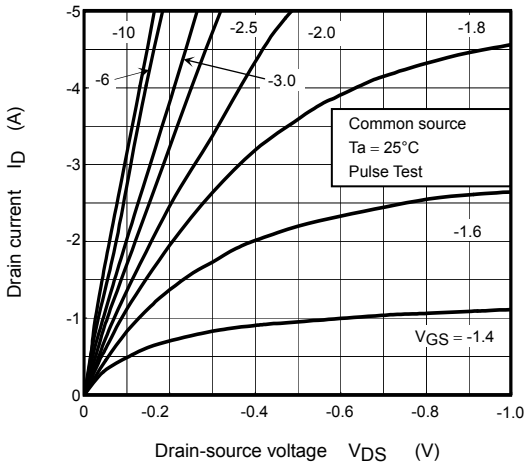
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	V_{GS} = ±10V, V_{DS} = 0 V	—	—	±10	μA
Drain cut-off current		I_{DSS}	V_{DS} = −20 V, V_{GS} = 0 V	—	—	−10	μA
Drain-source breakdown voltage		$V_{(BR)\ DSS}$	I_D = −10 mA, V_{GS} = 0 V	−20	—	—	V
		$V_{(BR)\ DSX}$	I_D = −10 mA, V_{GS} = 10 V	−10	—	—	
Gate threshold voltage		V_{th}	V_{DS} = −10 V, I_D = −200 μA	−0.5	—	−1.2	V
Drain-source ON resistance		$R_{DS\ (ON)}$	V_{GS} = −2.0 V, I_D = −1.5 A	—	100	200	mΩ
		$R_{DS\ (ON)}$	V_{GS} = −2.5 V, I_D = −1.5 A	—	68	95	
		$R_{DS\ (ON)}$	V_{GS} = −4.5 V, I_D = −1.5 A	—	44	59	
Forward transfer admittance		$\|Y_{fs}\|$	V_{DS} = −10 V, I_D = −1.5 A	3.1	6.2	—	S
Input capacitance		C_{iss}	V_{DS} = −10 V, V_{GS} = 0 V, f = 1 MHz	—	800	—	pF
Reverse transfer capacitance		C_{rss}		—	120	—	
Output capacitance		C_{oss}		—	160	—	
Switching time	Rise time	t_r		—	6.2	—	ns
	Turn-on time	t_{on}		—	15	—	
	Fall time	t_f		—	17	—	
	Turn-off time	t_{off}		—	51	—	
Total gate charge (gate-source plus gate-drain)		Q_g	V_{DD} ≃ −16 V, V_{GS} = −5 V, I_D = −3 A	—	11	—	nC
Gate-source charge1		Q_{gs1}		—	1.1	—	
Gate-drain (“miller”) charge		Q_{gd}		—	3.3	—	

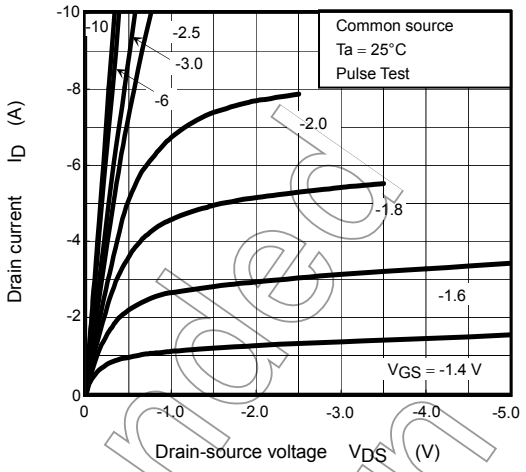
Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current	Pulse (Note 1)	I_{DRP}	—	—	—	−12	A
Forward voltage (diode)		V_{DSF}	I_{DR} = −3.0 A, V_{GS} = 0 V	—	—	1.2	V

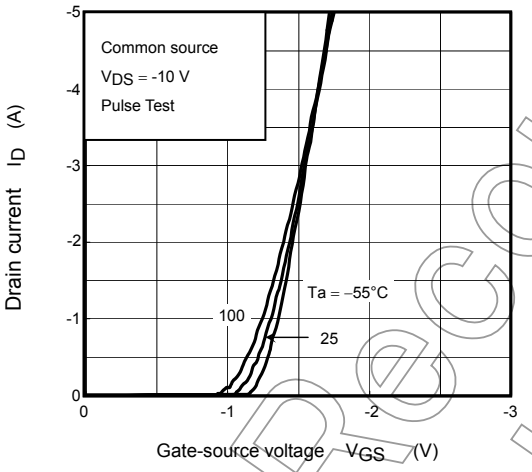
$I_D - V_{DS}$



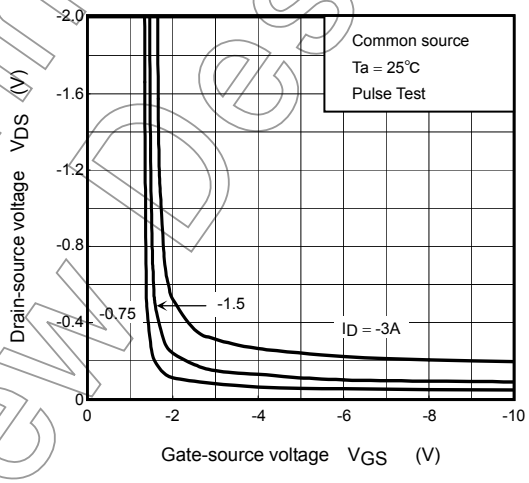
$I_D - V_{DS}$



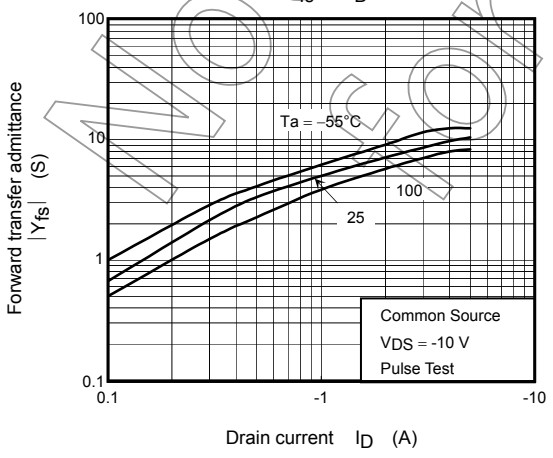
$I_D - V_{GS}$



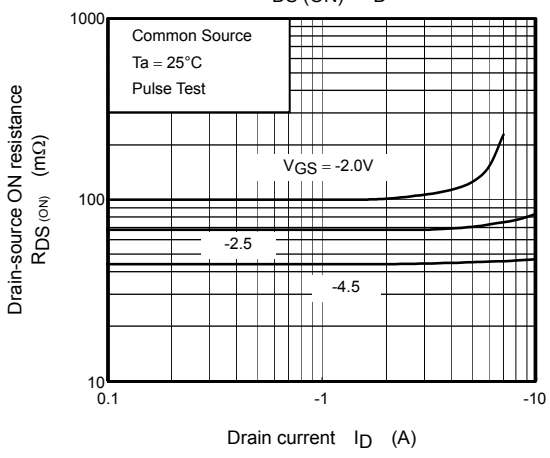
$V_{DS} - V_{GS}$



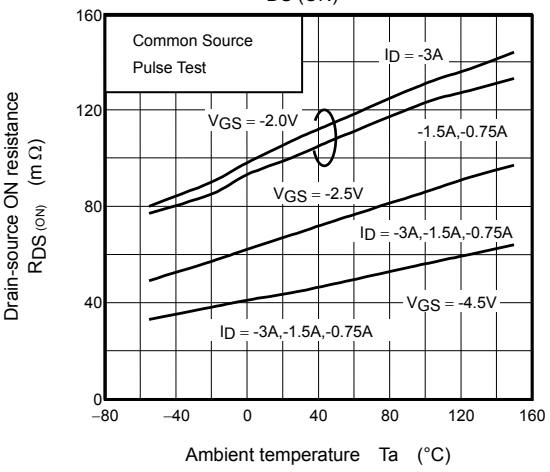
$|Y_{fs}| - I_D$



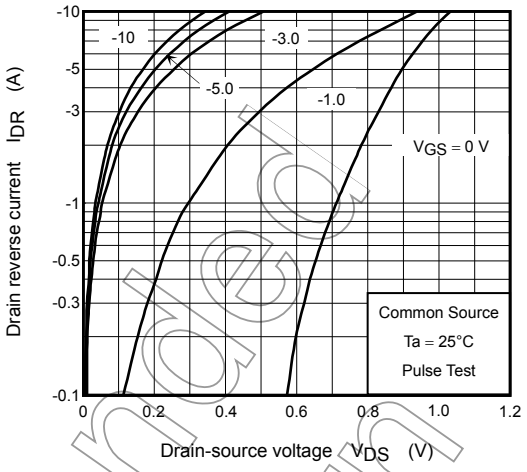
$R_{DS\ (ON)} - I_D$



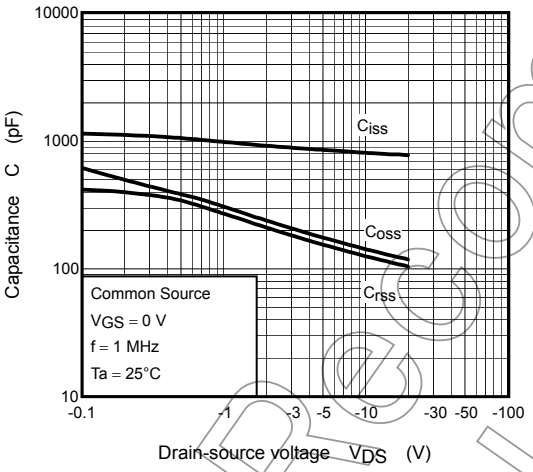
$R_{DS\ (ON)}$ – Ta



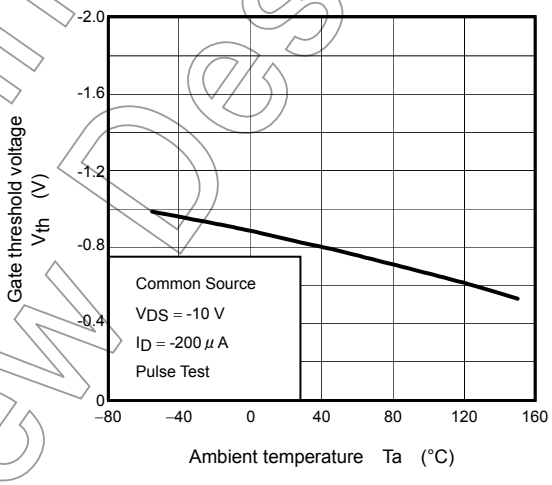
I_{DR} – V_{DS}



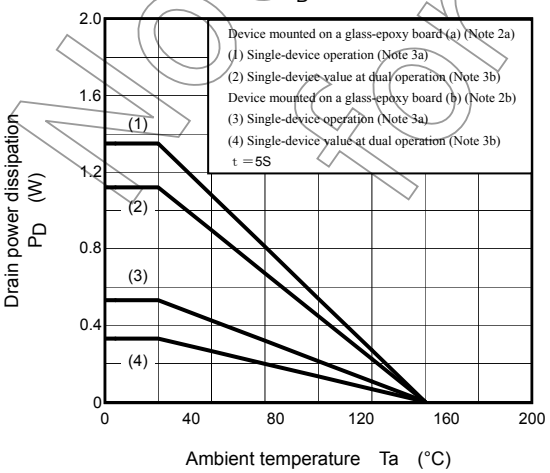
Capacitance – V_{DS}



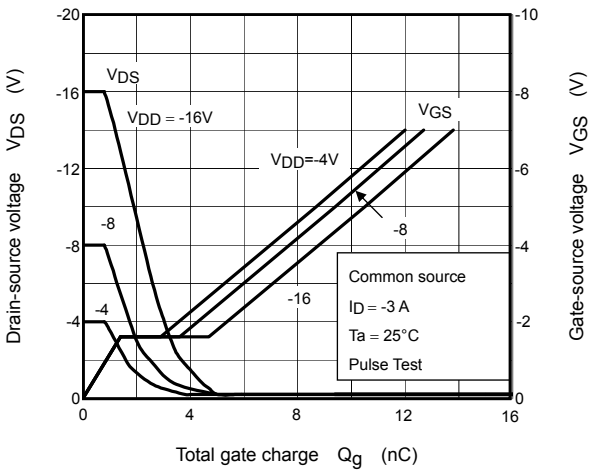
V_{th} – Ta



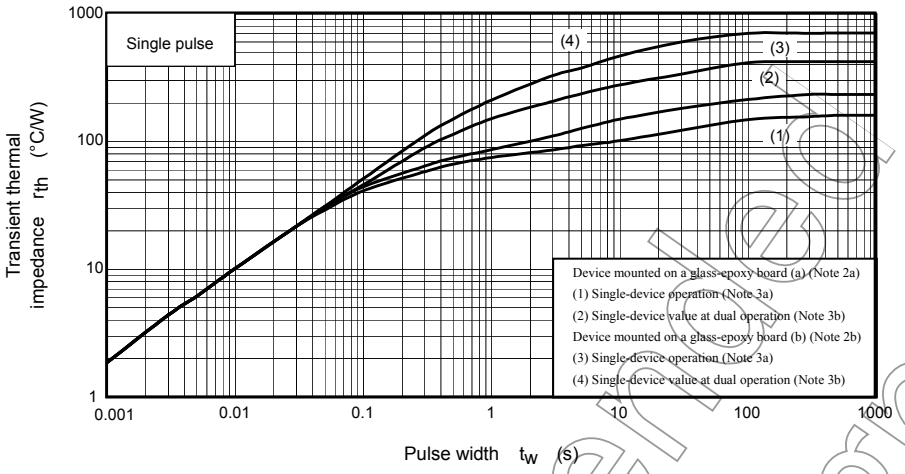
P_D – Ta



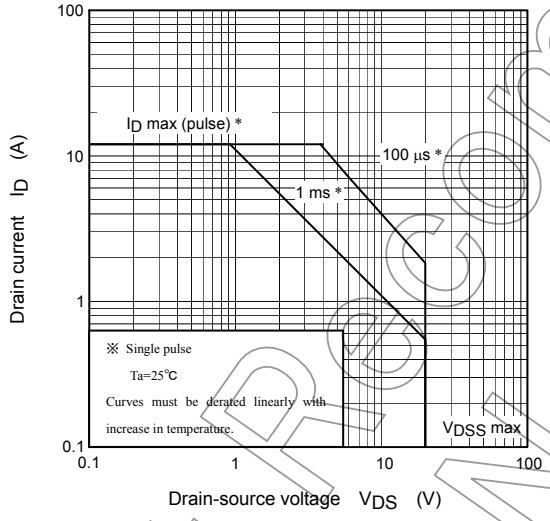
Dynamic input / output characteristics



$r_{th} - t_w$



Safe Operating Area



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